

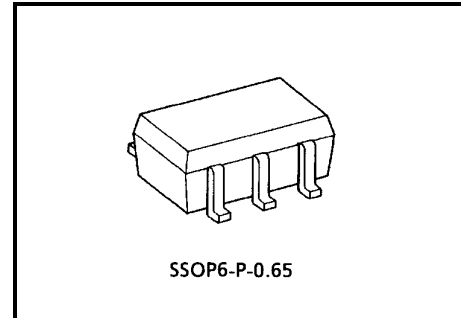
TG2210FT

RF SPDT Switch

Switch the receive filter for mobile communication.
 Switch the diversity antenna.
 Switch the local signal.

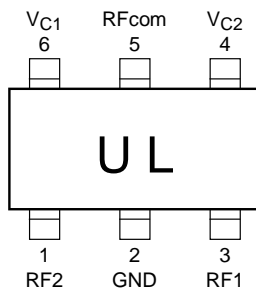
Features

- Low insertion Loss: LOSS = 0.4dB (typ.)
- High isolation: ISL = 30dB (typ.)
- Low voltage operation: $V_C = 0\text{ V}/2.5\text{ V}$
- Small package: TU6 package (2.0 × 1.25 × 0.6 mm)



Weight: 0.008 g (typ.)

Pin Connection, Marking (top view)



Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Control voltage	V_{C1}	5	V
	V_{C2}	5	V
Input power	P_i	1	W
Operating temperature range	T_{opr}	-40~85	°C
Storage temperature range	T_{stg}	-55~125	°C

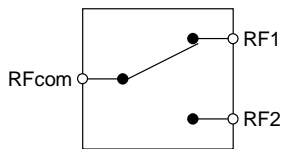
Caution

This device is sensitive to electrostatic discharge. When using this device, please ensure that all tools and equipment are earthed.

Electrical Characteristics (f = 1 GHz, Ta = 25°C, Zg = Zl = 50 Ω)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Insertion Loss	LOSS (1)	1	$V_{C1} = 2.5 \text{ V}, V_{C2} = 0 \text{ V}, P_i = 0 \text{ dBmW}$	—	0.4	0.7	dB
	LOSS (2)	1	$V_{C1} = 0 \text{ V}, V_{C2} = 2.5 \text{ V}, P_i = 0 \text{ dBmW}$	—	0.4	0.7	dB
Isolation	ISL (1)	1	$V_{C1} = 2.5 \text{ V}, V_{C2} = 0 \text{ V}, P_i = 0 \text{ dBmW}$	27	30	—	dB
	ISL (2)	1	$V_{C1} = 0 \text{ V}, V_{C2} = 2.5 \text{ V}, P_i = 0 \text{ dBmW}$	27	30	—	dB
Input power at 1dB gain compression	P_{i1dB}	1	$V_{C1} = 2.5 \text{ V}, V_{C2} = 0 \text{ V}$ or $V_{C1} = 0 \text{ V}, V_{C2} = 2.5 \text{ V}$	18	—	—	dBmW
Control current	I_{C1}	—	$V_{C1} = 0 \text{ V}, V_{C2} = 3 \text{ V}$ or $V_{C1} = 3 \text{ V}, V_{C2} = 0 \text{ V}$	—	—	0.01	mA
	I_{C2}	—		—	—	0.01	mA
Switching time	t_{sw}	—	$V_{C1} = 0 \text{ V}, V_{C2} = 2.5 \text{ V}$ or $V_{C1} = 2.5 \text{ V}, V_{C2} = 0 \text{ V}$	—	200	—	ns

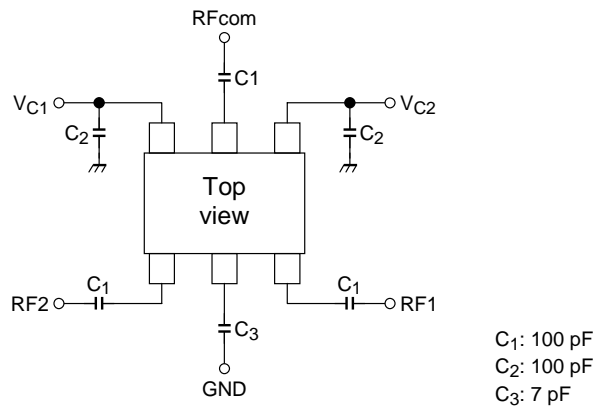
Block Diagram



Switch Condition

Control Voltage	Switch Condition
$V_{C1} = 2.5 \text{ V}$ $V_{C2} = 0 \text{ V}$	RFcom — RF1 OFF RFcom — RF2 ON
$V_{C1} = 0 \text{ V}$ $V_{C2} = 2.5 \text{ V}$	RFcom — RF1 ON RFcom — RF2 OFF

Test Circuit 1 (RF Test Circuit)



Please fix the value of each capacity for using frequency and circuit.

Recommend Capacity

	1 GHz	1.6 GHz	2.4 GHz
C ₁	100 pF	100 pF	100 pF
C ₂	100 pF	100 pF	100 pF
C ₃	7 pF	3 pF	1.5 pF

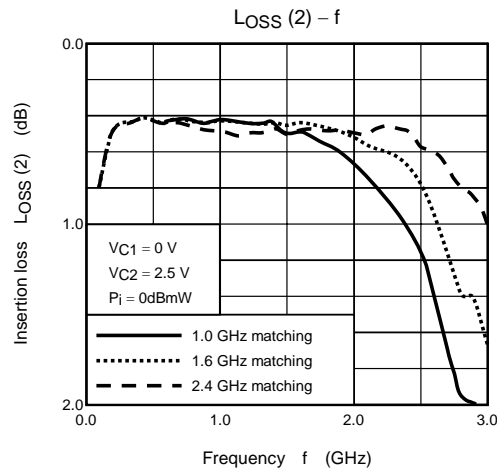
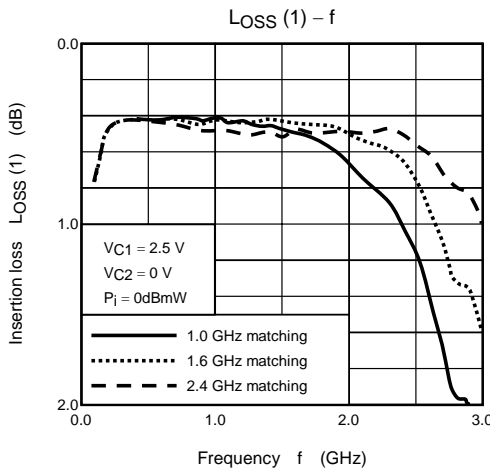
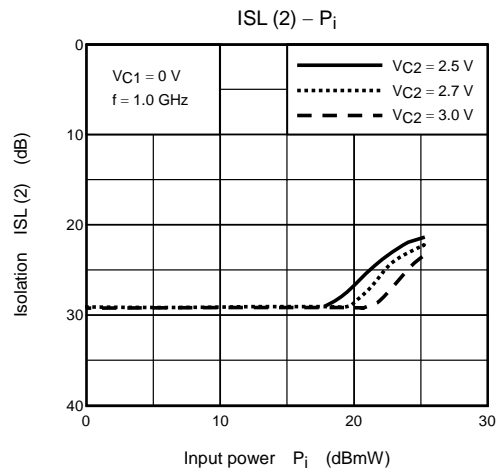
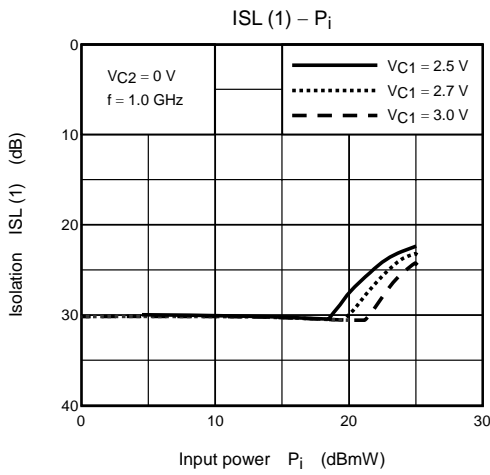
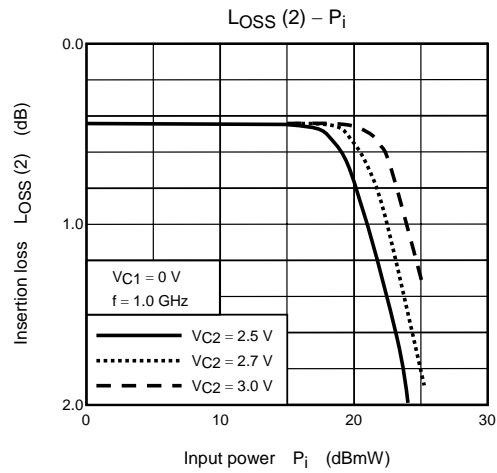
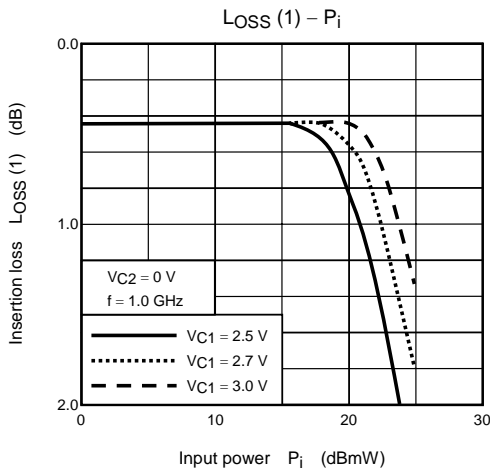
Notice

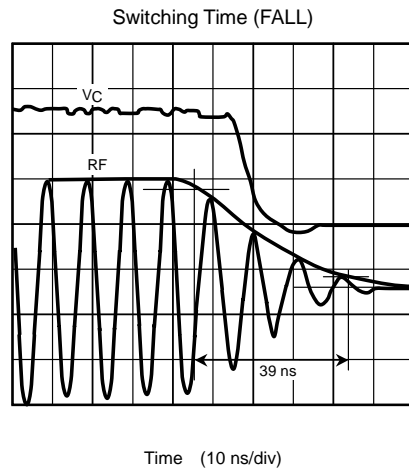
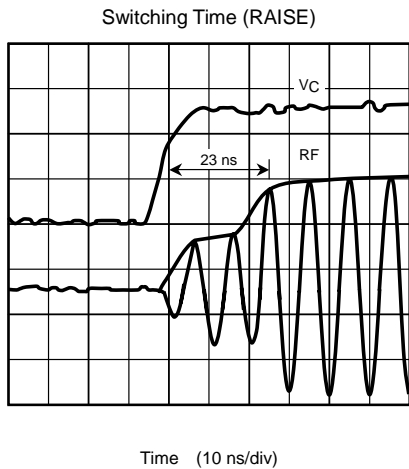
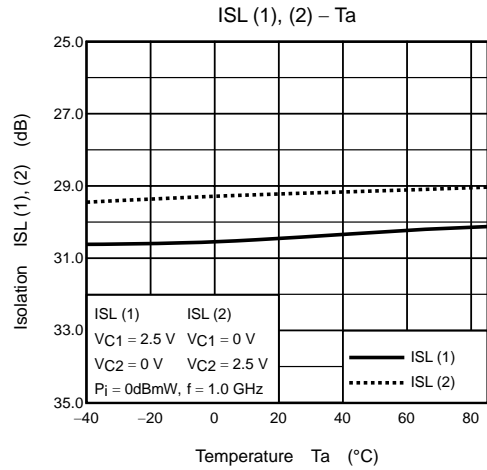
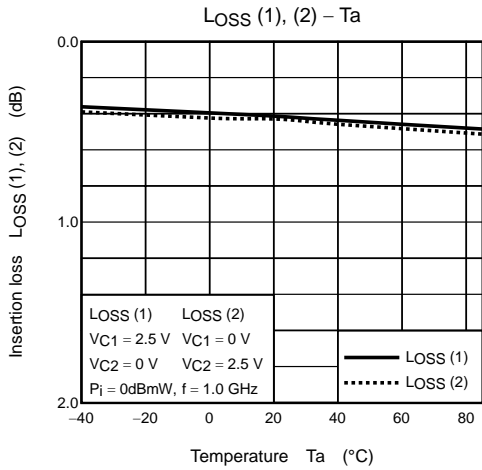
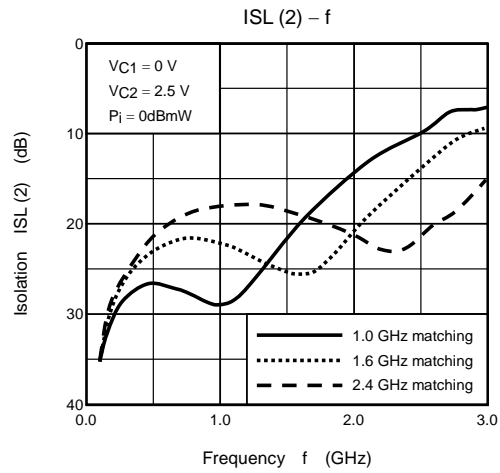
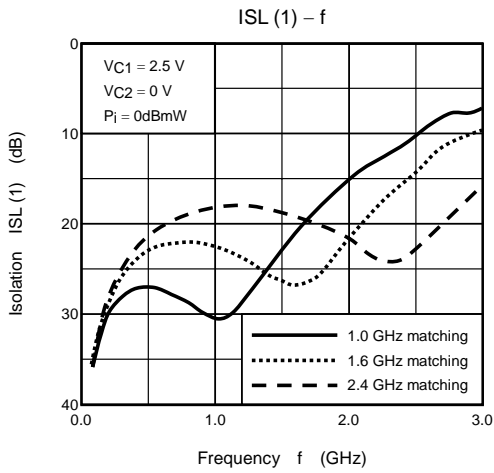
The circuits and measurements contained in this document are given only in the context of as examples of applications for these products.

Moreover, these example application circuits are not intended for mass production, since the high-frequency characteristics (the AC characteristics) of these devices will be affected by the external components which the customer uses, by the design of the circuit and by various other conditions.

It is the responsibility of the customer to design external circuits which correctly implement the intended application, and to check the characteristics of the design.

TOSHIBA assume no responsibility for the integrity of customer circuit designs or applications.

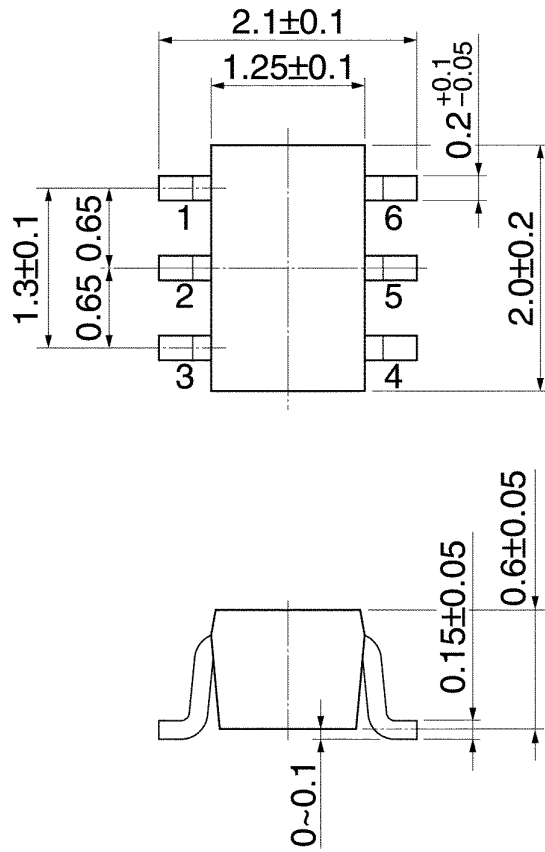




Package Dimensions

SSOP6-P-0.65

Unit: mm



Weight: 0.008 g (typ.)

RESTRICTIONS ON PRODUCT USE

020704EAC

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